DATA SHEET



MOS FIELD EFFECT TRANSISTOR $\mu PA1723$

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The μ PA1723 is N-Channel MOS Field Effect Transistor designed for power management switch.

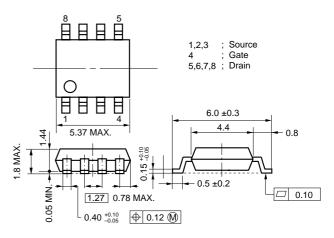
FEATURES

- Low on-state resistance
- $R_{DS(on)1} = 6.7 \ m\Omega \ MAX. \ (V_{GS} = 4.5 \ V, \ I_{D} = 7.0 \ A) \\ R_{DS(on)2} = 7.4 \ m\Omega \ MAX. \ (V_{GS} = 4.0 \ V, \ I_{D} = 7.0 \ A) \\ R_{DS(on)3} = 8.7 \ m\Omega \ MAX. \ (V_{GS} = 2.5 \ V, \ I_{D} = 7.0 \ A)$
- Low Ciss : Ciss = 3800 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

ORDERING INFORMATION

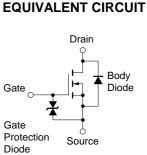
PART NUMBER	PACKAGE
μΡΑ1723G	Power SOP8

PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (VGs = 0 V)	VDSS	20	V	1
Gate to Source Voltage (VDS = 0 V)	Vgss	±12	V	
Drain Current (DC)	D(DC)	±13	А	
Drain Current (pulse) ^{Note1}	D(pulse)	±52	А	
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note2}$	Рт	2.0	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	-55 to + 150	°C	



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Mounted on ceramic substrate of 1200 mm² x 2.2mm

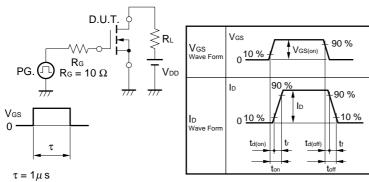
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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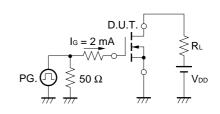
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNI
Drain to Source On-state Resistance	RDS(on)1	Vgs = 4.5 V, Id = 7.0 A		5.4	6.7	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 7.0 A		5.5	7.4	mΩ
	RDS(on)3	Vgs = 2.5 V, Id = 7.0 A		6.5	8.7	mΩ
Gate to Source Cut-off Voltage	VGS(off)	V _{DS} = 10 V, I _D = 1 mA	0.5	0.9	1.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 7.0 A	15.0	32		S
Drain Leakage Current	IDSS	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 12 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		3800		pF
Output Capacitance	Coss	V _G s = 0 V		1200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		700		pF
Turn-on Delay Time	td(on)	ID = 7.0 A		70		ns
Rise Time	tr	$V_{GS(on)} = 4.5 V$		440		ns
Turn-off Delay Time	td(off)	Vdd = 10 V		230		ns
Fall Time	tr	R _G = 10 Ω		300		ns
Total Gate Charge	QG	ID = 13 A		47.0		nC
Gate to Source Charge	Q _{GS}	Vdd = 16 V		11.0		nC
Gate to Drain Charge	Qgd	Vgs = 4.5 V		12.0		nC
Body Diode Forward Voltage	VF(S-D)	IF = 13.0 A, VGs = 0 V		0.75		V
Reverse Recovery Time	trr	IF = 13.0 A, VGs = 0 V		68		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		70		nC

ELECTRICAL CHARACTERISTICS (TA = 25 °C, All terminals are connected.)

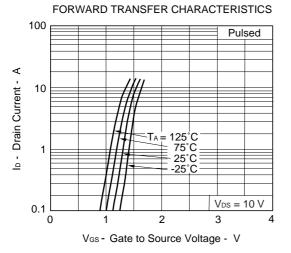
TEST CIRCUIT 1 SWITCHING TIME

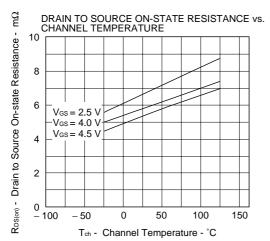


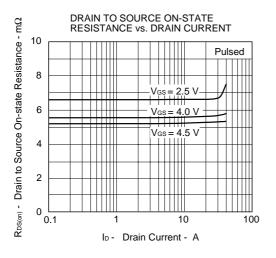
TEST CIRCUIT 2 GATE CHARGE

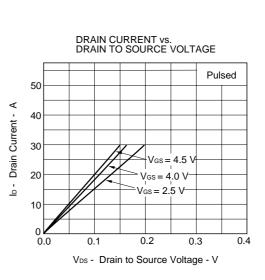


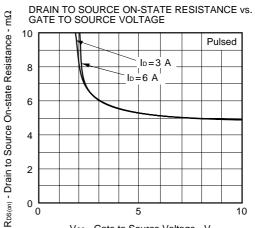
 $\tau = 1\mu s$ Duty Cycle $\leq 1 \%$ ★ TYPICAL CHARACTERISTICS (T_A = 25 °C)





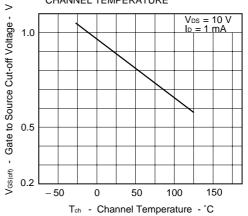


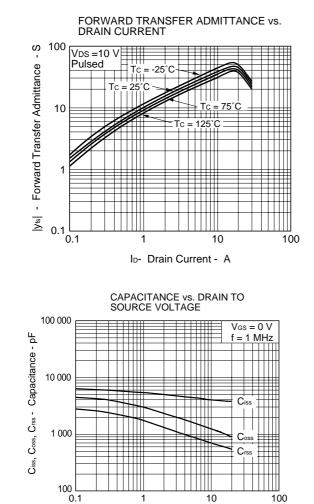




VGS - Gate to Source Voltage - V

GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



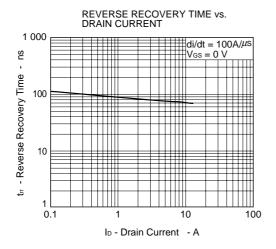


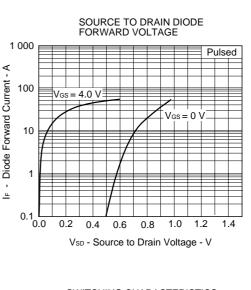


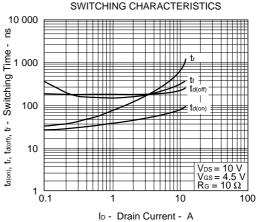
NEC

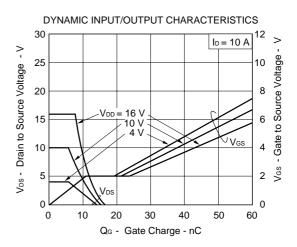
Mounted on ceramic substrate of 1200 $\rm mm^2~x~2.2~mm$

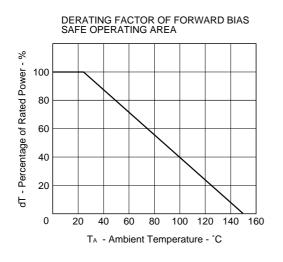
VDS - Drain to Source Voltage - V

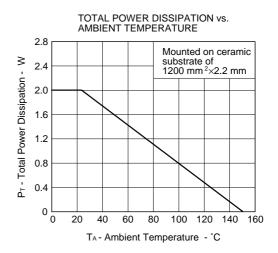


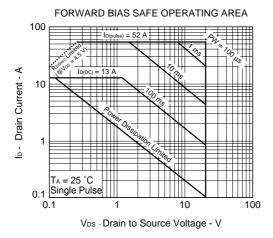






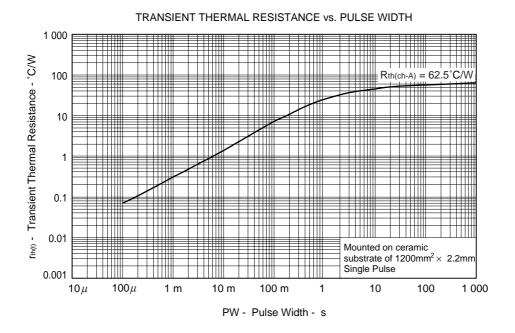






Remark Mounted on ceramic substrate of 1200 mm² x

Mounted on ceramic substrate of 1200 mm² x 2.2 mm



Data Sheet G14026EJ1V0DS00

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